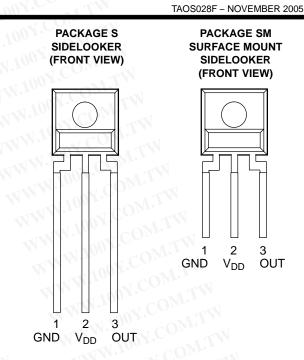
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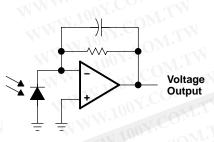
- Monolithic Silicon IC Containing Photodiode, Operational Amplifier, and Feedback Components
- Converts Light Intensity to a Voltage
- High Irradiance Responsivity, Typically 137 mV/(μW/cm²) at λ_p = 635 nm (TSL250R)
- Compact 3-Lead Clear Plastic Package
- Single Voltage Supply Operation
- Low Dark (Offset) Voltage....10 mV Max
- Low Supply Current.....1.1 mA Typical
- Wide Supply-Voltage Range.... 2.7 V to 5.5 V
- Replacements for TSL250, TSL251, and TSL252
- RoHS Compliant (–LF Package Only)



Description

The TSL250R, TSL251R, and TSL252R are light-to-voltage optical sensors, each combining a photodiode and a transimpedance amplifier (feedback resistor = $16 M\Omega$, $8 M\Omega$, and $2.8 M\Omega$ respectively) on a single monolithic IC. Output voltage is directly proportional to the light intensity (irradiance) on the photodiode. These devices have improved amplifier offset-voltage stability and low power consumption and are supplied in a 3-lead clear plastic sidelooker package with an integral lens. When supplied in the lead (Pb) free package, the device is RoHS compliant.

Functional Block Diagram



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Available Options

DEVICE	TA	PACKAGE – LEADS	PACKAGE DESIGNATOR	ORDERING NUMBER
TSL250R	0°C to 70°C	3-lead Sidelooker	S	TSL250R
TSL250R	0°C to 70°C	3-lead Sidelooker — Lead (Pb) Free	S	TSL250R-LF
TSL250R	0°C to 70°C	3-lead Surface-Mount Sidelooker — Lead (Pb) Free	SM	TSL250RSM-LF
TSL251R	0°C to 70°C	3-lead Sidelooker	S	TSL251R
TSL251R	0°C to 70°C	3-lead Sidelooker — Lead (Pb) Free	S	TSL251R-LF
TSL251R	0°C to 70°C	3-lead Surface-Mount Sidelooker — Lead (Pb) Free	SM	TSL251RSM-LF
TSL252R	0°C to 70°C	3-lead Sidelooker	CS	TSL252R
TSL252R	0°C to 70°C	3-lead Sidelooker — Lead (Pb) Free	S	TSL252R-LF
TSL252R	0°C to 70°C	3-lead Surface-Mount Sidelooker — Lead (Pb) Free	SM	TSL252RSM-LF

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Terminal Functions

	INAL NO.	DESCRIPTION
GND	1	Ground (substrate). All voltages are referenced to GND.
OUT	3	Output voltage
V _{DD}	2	Supply voltage

Absolute Maximum Ratings over operating free-air temperature range (unless otherwise noted)[†] WWW.10

Supply voltage, V _{DD} (see Note 1)	6 V
Output current, I _O	
Duration of short-circuit current at (or below) 25°C (see Note 2)	
Operating free-air temperature range, T _A	
Storage temperature range, T _{stg}	–25°C to 85°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability. WWW.100Y.COM.?

NOTES: 1. All voltages are with respect to GND.

Recommended Operating Conditions

WW.IOUN CONT.	WWW.Low COM	MIN	NOM	MAX	UNIT
Supply voltage, V _{DD}	W.IOU CON.	2.7	1.100	5.5	V
Operating free-air temperature, T _A	W	0	W.100	70	°C

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	W W	TEST	TT.	SL250R		Ţ	SL251R		TYT	SL252R	l	
	PARAMETER	CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
VD	Dark voltage	$E_e = 0$	0	4	10	0	4	10	0	4	10	mV
V _{OM}	Maximum output voltage	V _{DD} = 4.5 V	3.0	3.3		3.0	3.3	oy.C	3.0	3.3		V
cO	Mr	$E_e = 14.6 \mu\text{W/cm}^2$	1.5	2	2.5	VIA	14.2		Ow	Wn		
Vo	Output voltage	$E_e = 38.5 \mu\text{W/cm}^2$	102	V. r.	đ	1.5	2	2.5	$c0^{NL}$			V
Y.C		$E_e = 196 \mu\text{W/cm}^2$		M.TY		N		700 1	1.5	2	2.5	1
ανο	Temperature coefficient of output voltage (V _O)	$E_{e} = 14.6 \mu W/cm^{2},$	N.CO	1.6	N	1	d Maria	100	TIM	VT.M		mV/°C
		$T_A = 0^\circ C$ to $70^\circ C$	V.C	0.08	W			N . 1 .				%/°C
		$E_{e} = 38.5 \mu W/cm^{2}$,		-0 _M .			1.6	N.10	ST C	ON.		mV/°C
		$T_A = 0^{\circ}C$ to $70^{\circ}C$	1001.		MT.		0.08	-N.1	M.I.	I.M.	%/°C	
		(O) $E_e = 196 \mu\text{W/cm}^2$,	1001	The second	VT.	4		001.	1.6	WT.	mV/°C	
1.70	CONT	$T_A = 0^{\circ}C$ to $70^{\circ}C$.10-	J.CO	NT-	N		NW.	Ynn	0.08	NT.	%/°C
N.1	Irradiance	$\lambda_p = 635 \text{ nm},$ See Notes 5 and 7	N.100	137	. I.M.	W	52	MMA	.100 x1 100	10.2	M.T	
N _e	responsivity	$\lambda_p = 880 \text{ nm},$ See Notes 6 and 7	W.	127	COM	TW	48	WW	W.10	9.4	OM.	mV/(µW/cm²
VV Y	1007.00	$E_e = 14.6 \mu\text{W/cm}^2$		1.1	1.7	U.T.W		AL.		002.	And	1.1
IDD	Supply current	$E_e = 38.5 \mu\text{W/cm}^2$	M.M.	100	1.00	VT.	1.1	1.7	N	1001.		mA
		$E_{e} = 196 \mu W/cm^{2}$	VINI	1.100	J CC	Mr	N	<	MM.	1.1	1.7	Wn

Electrical Characteristics at V_{DD} = 5 V, T_A = 25°C, λ p = 635 nm, R_L = 10 k Ω (unless otherwise noted) (see Notes 3, 4, and 5)

NOTES: 3. Measurements are made with $R_L = 10 k\Omega$ between output and ground.

4. Optical measurements are made using small-angle incident radiation from an LED optical source.

5. The input irradiance E_e is supplied by an AlInGaP LED with peak wavelength λ_p = 635 nm

6. The input irradiance E_e is supplied by a GaAlAs LED with peak wavelength λ_p = 880 nm

7. Irradiance responsivity is characterized over the range $V_0 = 0.05$ to 2.9 V. The best-fit straight line of Output Voltage V_0 versus irradiance E_e over this range will typically have a positive extrapolated V_0 value for $E_e = 0$.

Dynamic Characteristics at $T_A = 25^{\circ}C$ (see Figure 1)

DADAMETER V.100			TSL250R			TSL251R			TSL252R			COM
	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	UNIT
tr	Output pulse rise time	$V_{DD} = 5 V$, $\lambda_p = 635 \text{ nm}$		260	1001		70		N	7	100°	μs
t _f	Output pulse fall time	$V_{DD} = 5 \text{ V}, \lambda_p = 635 \text{ nm}$	2	260		I.CU	70	N		7	110	μs
Vn	Output noise voltage	$V_{DD} = 5 V, E_e = 0, \\ f = 1000 \text{ Hz}$		0.8	N.10	N.CC	0.7	LM.		0.6	W.1	μV/√Hz

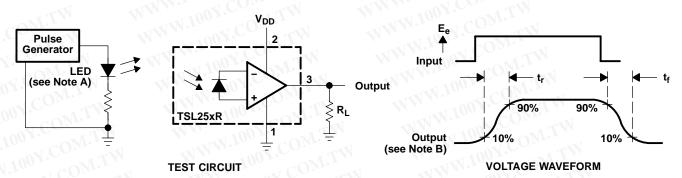
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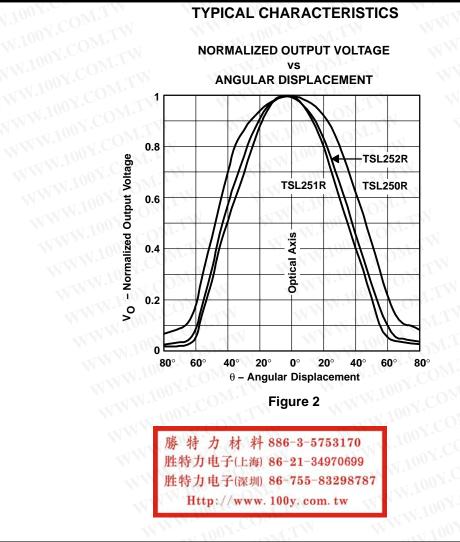




NOTES: A. The input irradiance is supplied by a pulsed AlInGaP light-emitting diode with the following characteristics: $\lambda_p = 635$ nm, $t_r < 1 \ \mu$ s.

B. The output waveform is monitored on an oscilloscope with the following characteristics: $t_r < 100$ ns, $Z_i \ge 1$ M Ω , $C_i \le 20$ pF.

Figure 1. Switching Times



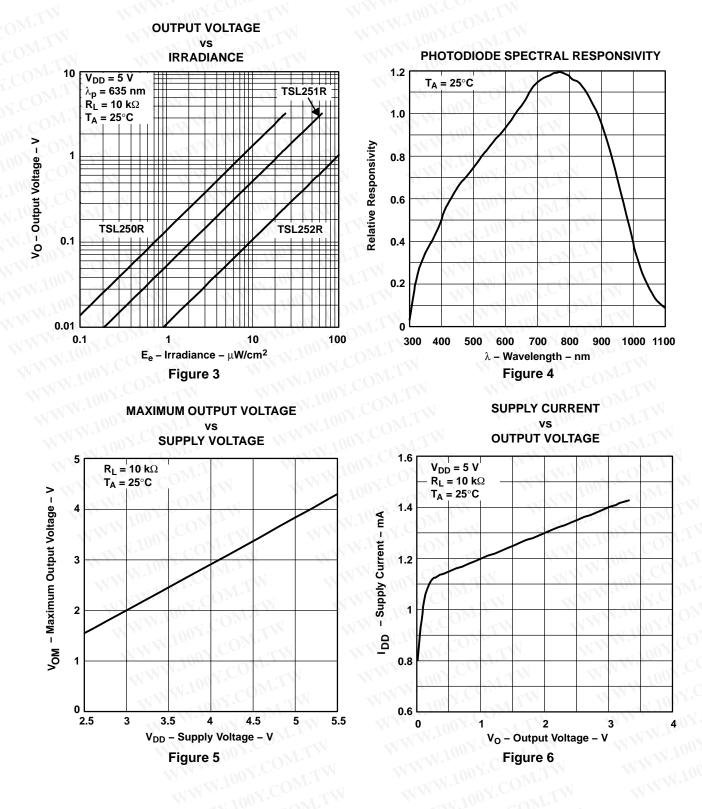
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TYPICAL CHARACTERISTICS





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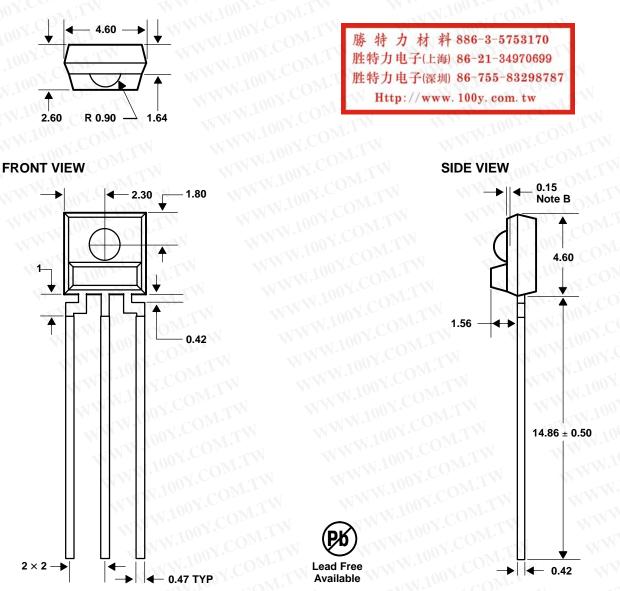
MECHANICAL INFORMATION

The devices are supplied in a clear plastic three-lead package (S). The integrated photodiode active area is typically 1,0 mm² (0.0016 in^2) for TSL250R, 0,5 mm² (0.00078 in^2) for the TSL251R, and 0,26 mm² (0.0004 in^2) for the TSL252R.

PACKAGE S

PLASTIC SINGLE-IN-LINE SIDE-LOOKER PACKAGE

TOP VIEW



NOTES: A. All linear dimensions are in millimeters; tolerance is \pm 0.25 mm unless otherwise stated.

- B. Dimension is to center of lens arc, which is located below the package face.
- C. The integrated photodiode active area is typically located in the center of the lens and 0.97 mm below the top of the lens surface.
- D. Index of refraction of clear plastic is 1.55.
- E. Lead finish for TSL25xR: solder dipped, 63% Sn/37% Pb. Lead finish for TSL25xR-LF: solder dipped, 100% Sn.
- F. This drawing is subject to change without notice.

Figure 7. Package Configuration

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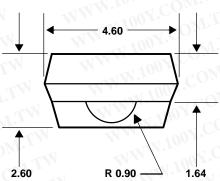
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PACKAGE SM

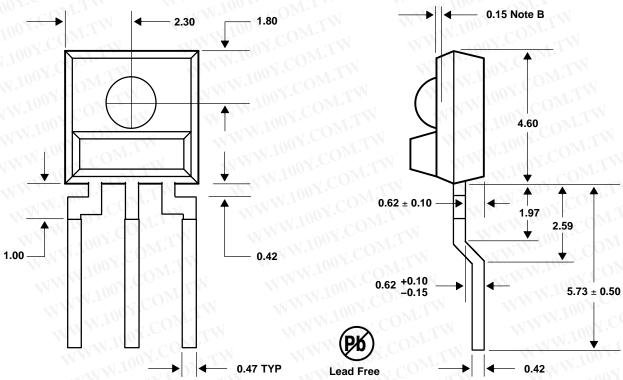
PLASTIC SURFACE MOUNT SIDE-LOOKER PACKAGE

TOP VIEW



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FRONT VIEW



SIDE VIEW

NOTES: A. All linear dimensions are in millimeters; tolerance is \pm 0.25 mm unless otherwise stated.

- B. Dimension is to center of lens arc, which is located below the package face.
- C. The integrated photodiode active area is typically located in the center of the lens and 0.97 mm below the top of the lens surface.
- D. Index of refraction of clear plastic is 1.55.

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- E. Lead finish for TSL25xRSM-LF: solder dipped, 100% Sn.
- F. This drawing is subject to change without notice.

Figure 8. Package SM — Surface Mount Side-Looker Package Configuration



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